

2-GHz Single Balanced Mixer

Description

The U2796B-FP is a 2-GHz down conversion mixer for telecommunication systems, e.g. cellular radio, CT1, CT2, DECT, PCN, using TELEFUNKEN advanced bipolar technology. The U2796B is well suited for the receiver

portion of the RF circuit. Single balanced structure has been chosen for the best noise performance and low current consumption. The IIP3 is programmable.

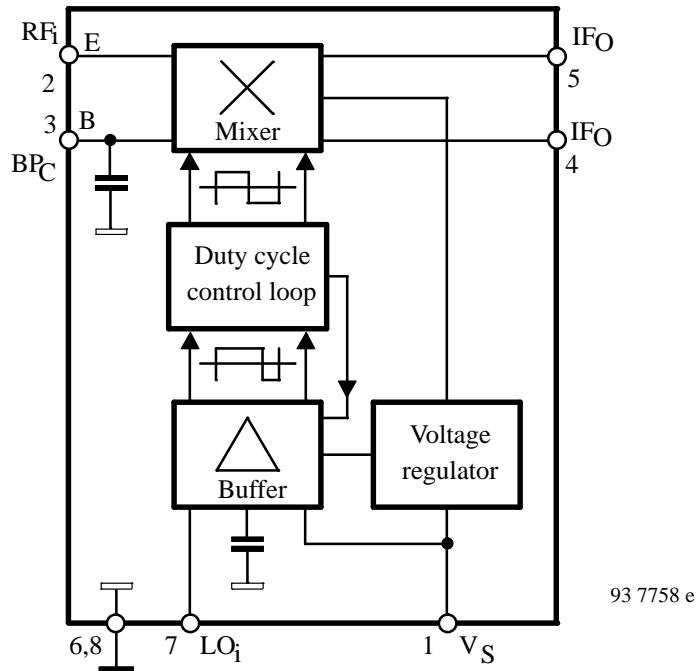
Features

- Supply voltage range: 2.7 to 5.5 V
- Excellent isolation characteristics
- Low current consumption: 3.2 mA without R_{IP3}
- IIP3 programmable
- Input frequency operating range up to 2 GHz
- RF characteristic nearly independent of supply voltage

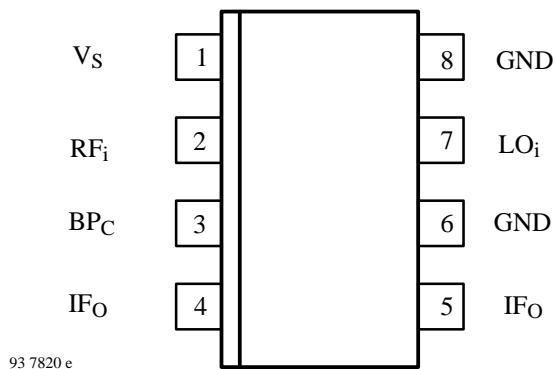
Benefits

- Stand alone product
- Low current consumption extends talk time
- 3-V operation requires small space for batteries

Block diagram



Pin out



Pin description

Pin	Symbol	Function
1	V _S	Supply voltage
2	RF	RF input and IIP3 programming port
3	B _P C	By-pass capacitor
4	IFo	IF output
5	IFo	IF output
6	GND	Ground
7	LO _i	Local oscillator input
8	GND	Ground

Absolute maximum ratings

Parameters	Symbol	Value	Unit
Supply voltage	V _S	6	V
Input voltage	V _i	0 to V _S	V
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	-40 to + 125	°C

Operating range

Parameters	Symbol	Value	Unit
Supply voltage range	V _S	2.7 to 5.5	V
Ambient temperature	T _{amb}	-40 to + 85	°C

Thermal resistance

Parameters	Symbol	Value	Unit
Junction ambient	R _{thJA}	175	K/W

Electrical characteristics

Test conditions (unless otherwise specified):

 $V_S = 3 \text{ V}$, $f_{LO} = 900 \text{ MHz}$; $I_M = 1.2 \text{ mA}$, $T_{amb} = 25^\circ\text{C}$. System impedance $Z_O = 50 \Omega$

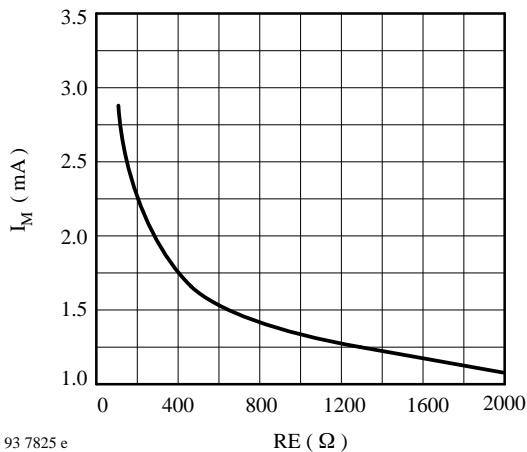
Parameters	Test conditions / Pin	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Pin 1	V_S	2.7		5.5	V
Supply current	$R_{IP3} = \infty$, Pin 1	I_S	2.8	3.2	3.7	mA
Conversion power gain	$RL = 3 \text{ k}\Omega$, $R_{IP3} = \infty$ $f_{LO} = 900 \text{ MHz}$	PG_C		9		dB
	$f_{LO} = 1700 \text{ MHz}$ $f_{IF} = 45 \text{ MHz}$			9		
Figure 4						
Isolation						
LO-spurious at RF_{in}	$P_{iLO} = -10 \text{ dBm}$ Figure 5	IS_{LORF}			-35	dBm
RF to LO	$P_{iRF} = -25 \text{ dBm}$ Pin 2 to 7	IS_{RFLO}	30	40		dB
	$f_{LO} = 900 \text{ MHz}$			20		
Figure 6	$f_{LO} = 1700 \text{ MHz}$					
Operating frequencies						
RF frequency	Pin 2	RF_i	2000			MHz
LO _{in} frequency	Pin 7	LO_i	2000			MHz
IF _{out} frequency	Pins 4 and 5	IF_o	300			MHz
Input level						
RF input (-1 dB comp.)	$RL = 50 \Omega$, Pin 2	P_{iRF}		-15		dBm
3rd order intercept point	$P_{iLO} = -10 \text{ dBm}$, $R_{IP3} = \infty$ Figure 2	$IIP3$		-4		dBm
LO input	Pin 7	P_{iLO}		-6	0	dBm
Impedances						
RF input	Pin 2	Z_{iRF}		25		Ω
LO input	Pin 7	Z_{iLO}		50		Ω
IF output	Pins 4 and 5	Z_{oIF}		$> 10 \text{ k}\Omega // 0.9 \text{ pF}$		
Noise figure (DSB)	$P_{iLO} = 0 \text{ dBm}$, $RL > 3 \text{ k}\Omega$ $f_{LO} = 900 \text{ MHz}$	NF_{50}		9		dB
	$f_{LO} = 1700 \text{ MHz}$			12		
Voltage standing wave ratio LO	Pin 7	$VSWR_{LO}$		1.3	2	

Note: I_M = Internal mixer current (see figure 2)

U2796B-FP

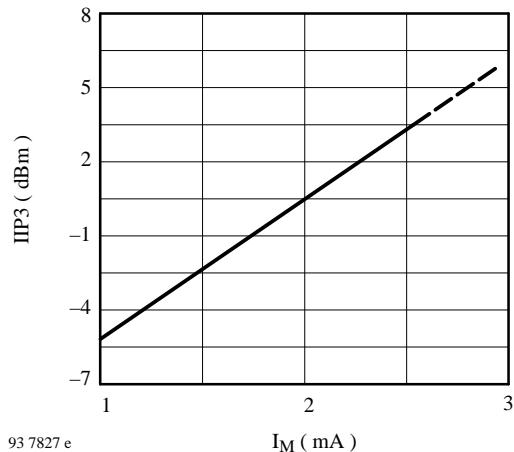
TEMIC

TELEFUNKEN Semiconductors



93 7825 e

Figure 1. Mixer current (I_M) versus R_E



93 7827 e

Figure 2. Third-order input intercept IIP_3 point versus I_M

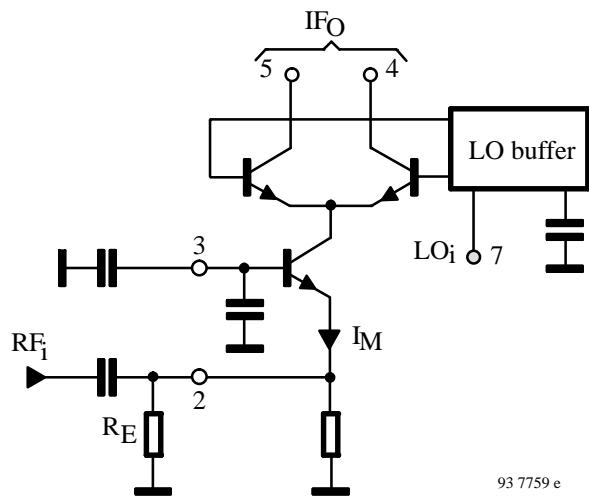


Figure 3. Mixer circuitry

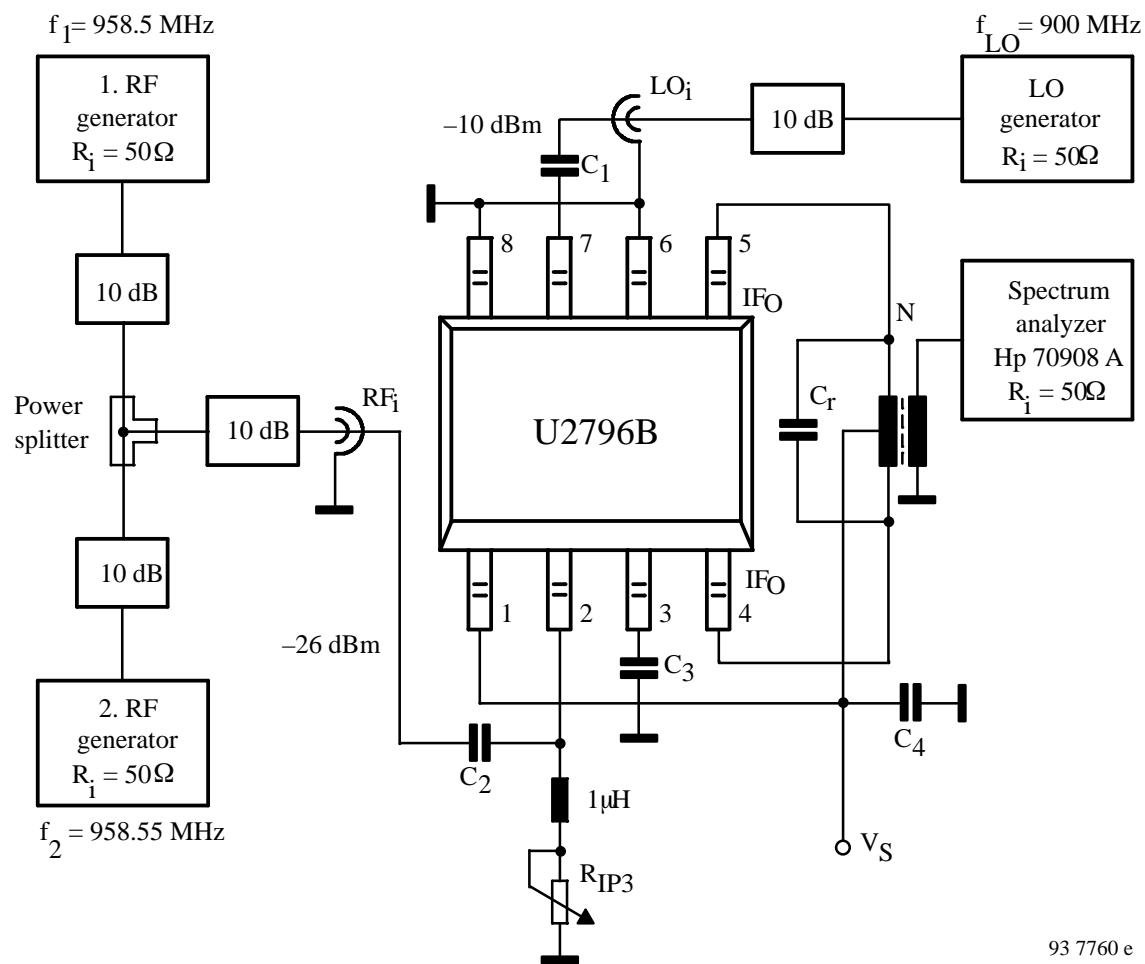


Figure 4. Test circuit-conversion power gain (PG_C) and 3rd order input intercept point (IIP3)

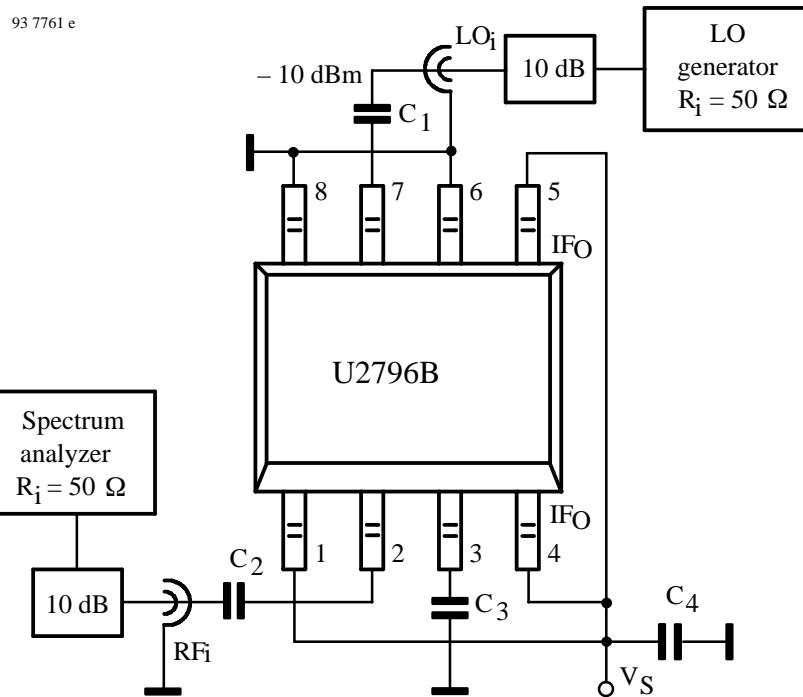


Figure 5. Test circuit-isolation LO to RF

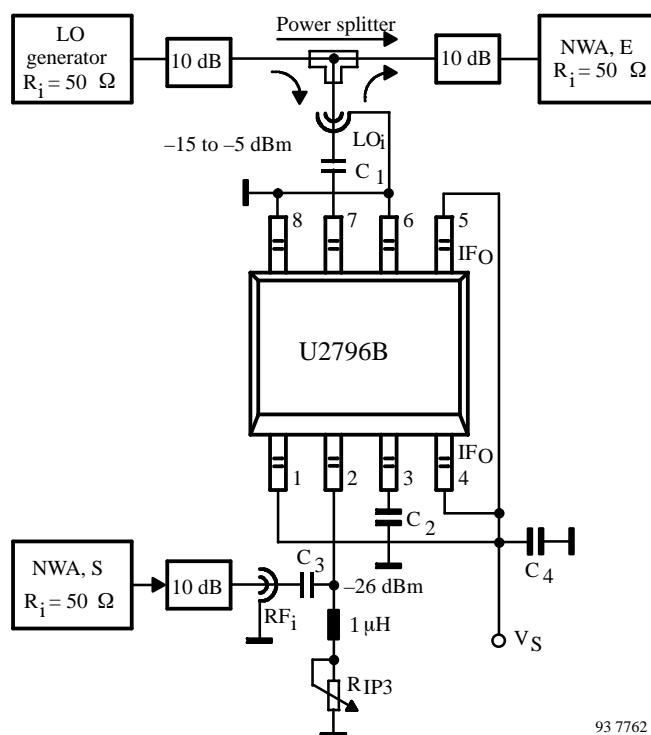
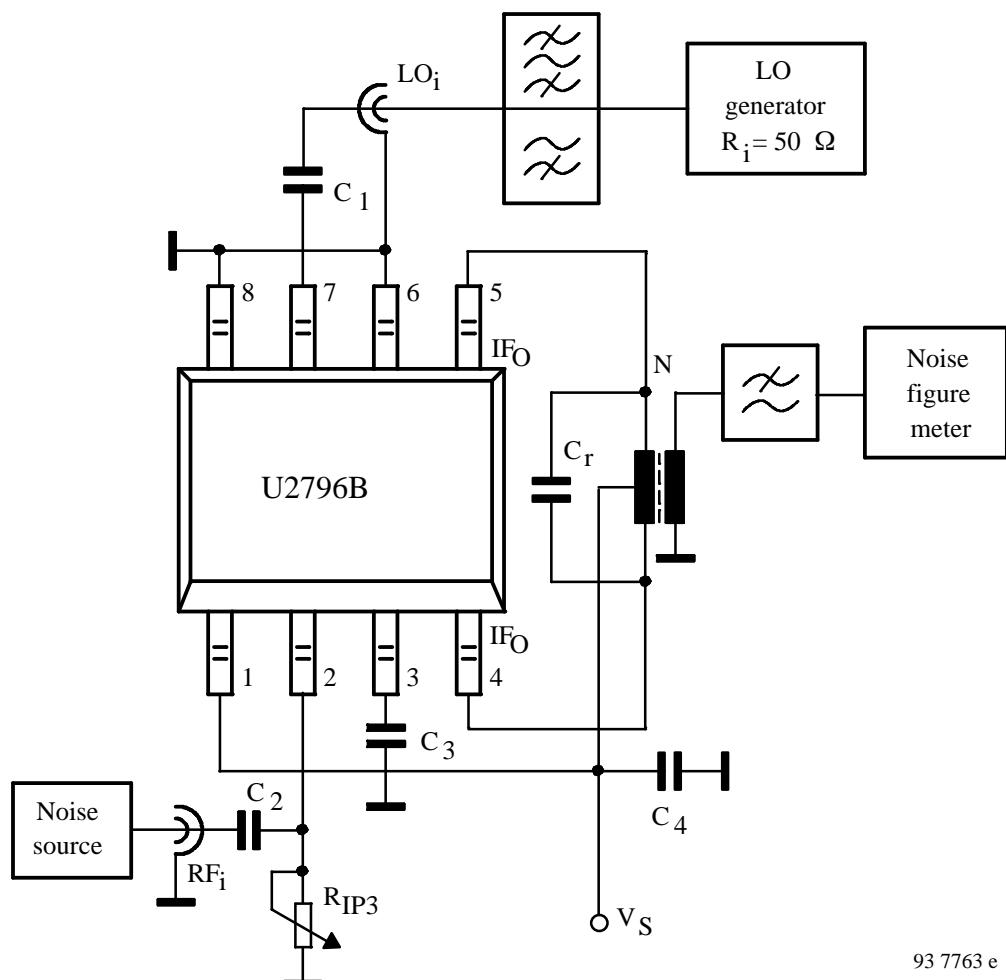


Figure 6. Test circuit-isolation RF to LO



93 7763 e

Figure 7. Test circuit-noise figure

Note:

1. The noise floor of the LO generator might influence the noise figure test result. In order to avoid this, either a band pass or a high pass filter with $f_c > f_{IF}$ should be implemented.
2. If IF output network does not provide sufficient suppression of the LO component, a low pass filter should be inserted to avoid overdriving the noise figure meter.
3. For best noise performance 0 dBm LO power level is required.

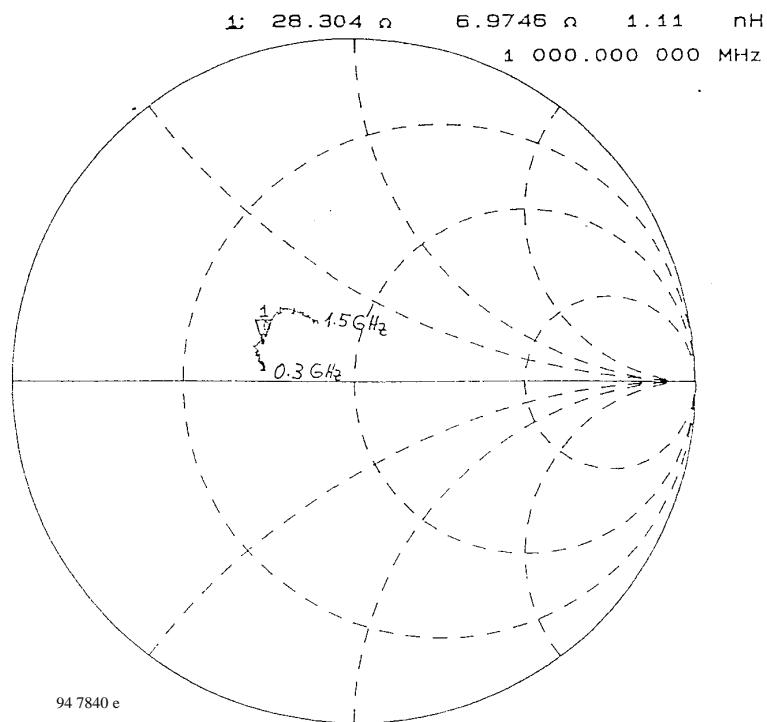


Figure 8. S11 RF input impedance

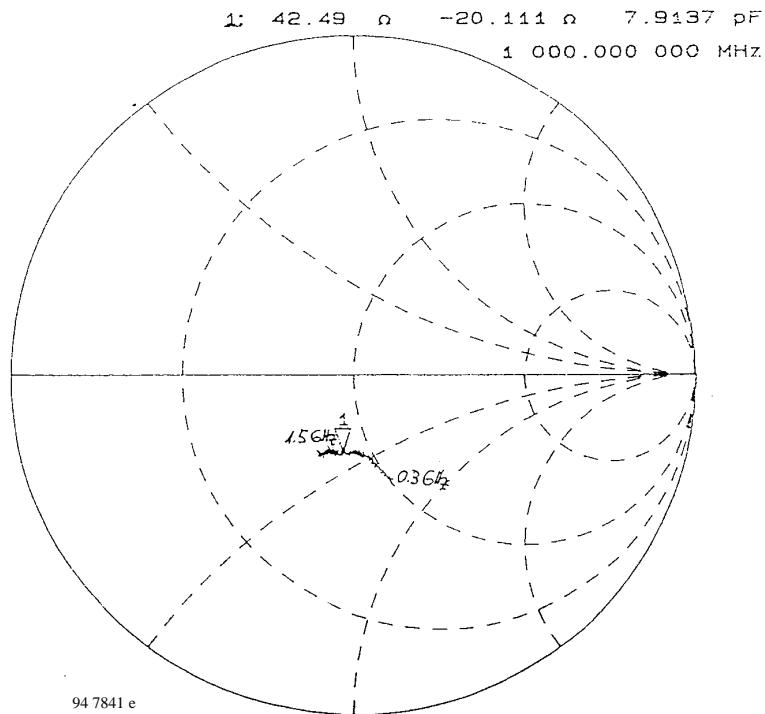


Figure 9. S11 LO input impedance

Application circuit

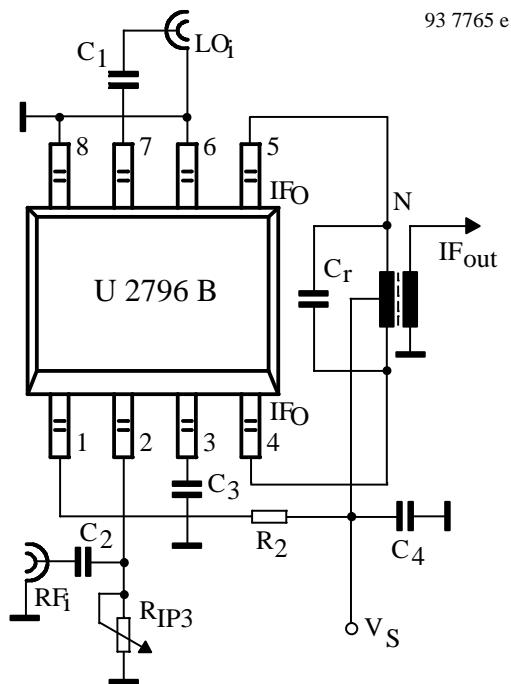


Figure 10

Recommended values for the evaluator

C_1 and $C_2 = 150 \text{ pF}$, C_3 and $C_4 = 100 \text{ nF}$. C_r is calculated for resonance with the balun at f_{IF} , or as a high pass filter for f_{LO} . The output balun transformer ratio $> 8:1$ for $Z_O = 50 \Omega$. R_2 increases the IF output level and is calculated from:

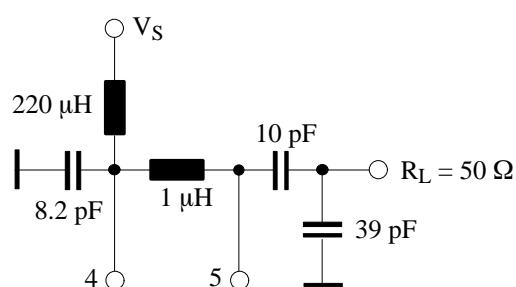
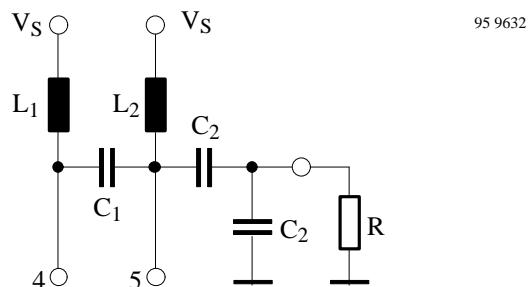
$$R_2 = \frac{V_S(4,5) - V_S(1)}{I_S(1)}$$

For example $V_S(4,5) = 4 \text{ V}$, $V_S(1) = 3 \text{ V}$, $I_S(1) = 2.2 \text{ mA}$ $R_2 \approx 470 \Omega$, where $I_S(1)$ is the current consumption without the mixer stage.

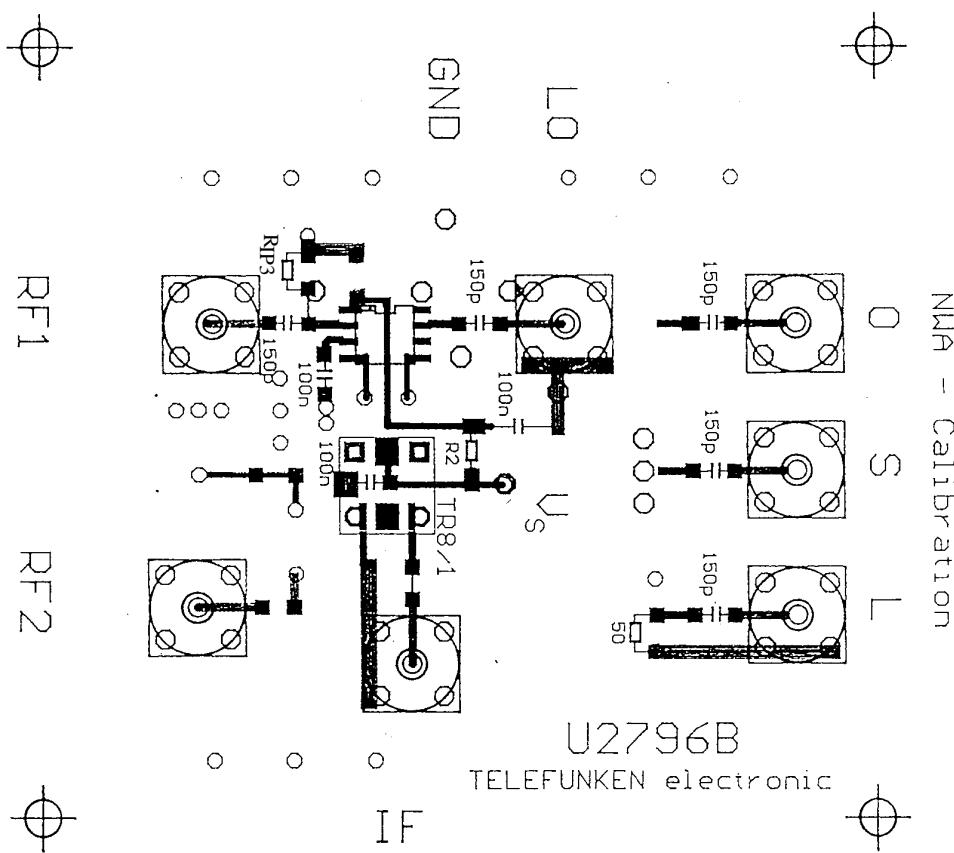
Application Hint

The output transformer at the pins 4 and 5 can be replaced by LC-circuits like one of the following proposals, which are saving space compared to the transformer and are suitable for higher IF frequencies. When applying one of these solutions, it has to be checked whether the requirements on noise figure and gain can be achieved.

The second circuit was dimensioned for approximately 130 MHz and a load resistance of $50\ \Omega$. If for instance the impedance of a subsequent filter is $1\ k\Omega$, the capacitive voltage divider may be left out.

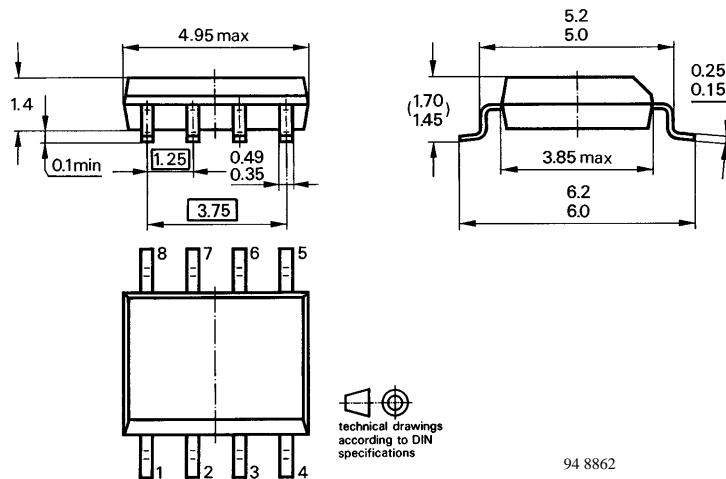


Evaluation board



Dimensions in mm

SO 8 package



We reserve the right to make changes to improve technical design without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax Number: 49 (0)7131 67 2423